

|          |  |   |            |     |
|----------|--|---|------------|-----|
| Prepared |  | <b>Product Specifications</b><br><b>AN7522N</b> | Ref No.    | A-1 |
| Checked  |  |   | Total Page | 9   |
| Approved |  |   | Page No.   | 1   |

|             |   |
|-------------|---|
| Structure   | Silicon Monolithic Bipolar IC   |
| Appearance  | SIL-12 Pin Plastic Package (Power Type with Fin)                            |
| Application | Low Frequency Amplifier   |
| Function    | BTL 5.0W x 2ch Power Amplifier<br>with Standby Function and Volume Function |

| A   | Absolute Maximum Ratings        |                |   |                         |         |
|-----|---------------------------------|----------------|---|-------------------------|---------|
| No. | Item                            | Symbol         | Ratings   | Unit                    | Note    |
| 1   | Storage Temperature             | Tstg           | -55 ~ +150  | ° C                     | 1       |
| 2   | Operating Ambient Temperature   | Topr           | -25 ~ +70   | ° C                     | 1       |
| 3   | Operating Ambient Pressure      | Popr           | $1.013 \times 10^5 \pm 0.61 \times 10^5$<br>( $1.0 \pm 0.6$ ) | Pa<br>(atm)             |         |
| 4   | Operating Constant Acceleration | Gopr           | 9,810<br>(1000)   | m/s <sup>2</sup><br>(G) |         |
| 5   | Operating Shock                 | Sopr           | 4,900<br>(500)  | m/s <sup>2</sup><br>(G) |         |
| 6   | Supply Voltage                  | Vcc            | 14.4  | V                       | 2       |
| 7   | Supply Current                  | Icc            | 2.0   | A                       |         |
| 8   | Power Dissipation               | P <sub>D</sub> | 1.92  | W                       | Ta=70°C |

|                                |     |              |
|--------------------------------|-----|--------------|
| Operating Supply Voltage Range | Vcc | 3.5V ~ 13.5V |
|--------------------------------|-----|--------------|

Note 1) The temperature of all items shall be Ta=25°C except storage temperature and operating ambient temperature.

2) At no signal input.

|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |   |            |     |
|----------|--|---|------------|-----|
| Prepared |  | <b>Product Specifications</b><br><b>AN7522N</b> | Ref No.    | B-1 |
| Checked  |  |   | Total Page | 9   |
| Approved |  |   | Page No.   | 2   |

| B  |                           | Electrical Characteristics (Unless otherwise specified, the ambient temperature is 25°C±2°C, Vcc=8.0V, frequency=1kHz and RL=8Ω.) |              |   |        |      |      |       |      |
|----|---------------------------|---|--------------|---|--------|------|------|-------|------|
| No | Item                      | Symbol  | Test Circuit | Conditions                              | Limits |      |      | Unit  | Note |
|    |                           |   |              |   | min    | typ  | max  |       |      |
| 1  | Quiescent Circuit Current | ICQ   | 1            | Vin=0V, Vol=0V                          | -      | 45   | 100  | mA    |      |
| 2  | Standby Current           | ISTB  | 1            | Vin=0V, Vol=0V                          | -      | 1    | 10   | μA    |      |
| 3  | Output Noise Voltage      | VNO   | 1            | Rg=10kΩ, Vol=0V                         | -      | 0.10 | 0.4  | mVrms | 1    |
| 4  | Voltage Gain              | Gv  | 1            | Po=0.5W, Vol=1.25V                      | 31     | 33   | 35   | dB    |      |
| 5  | Total Harmonic Distortion | THD   | 1            | Po=0.5W, Vol=1.25V                      | -      | 0.10 | 0.5  | %     |      |
| 6  | Maximum Power Output 1    | PO1   | 1            | THD=10%, Vol=1.25V                      | 2.4    | 3.0  | -    | W     |      |
| 7  | Maximum Power Output 2    | PO2   | 1            | Vcc=11V<br>THD=10%, Vol=1.25V           | 4.0    | 5.0  | -    | W     |      |
| 8  | Ripple Rejection Ratio    | RR  | 1            | Rg=10kΩ, Vol=0V<br>Vr=0.5Vrms, fr=120Hz | 30     | 50   | -    | dB    | 1    |
| 9  | Output Offset Voltage     | Voff  | 1            | Rg=10kΩ, Vol=0V                         | -250   | 0    | 250  | mV    |      |
| 10 | Volume Attenuation Ratio  | Att   | 1            | Po=0.5W, Vol=0V                         | 70     | 85   | -    | dB    | 1    |
| 11 | Channel Balance 1         | CB1   | 1            | Po=0.5W, Vol=1.25V                      | -1     | 0    | 1    | dB    |      |
| 12 | Channel Balance 2         | CB2   | 1            | Po=0.5W, Vol=0.6V                       | -2     | 0    | 2    | dB    |      |
| 13 | Middle Voltage Gain       | Gvm   | 1            | Po=0.5W, Vol=0.6V                       | 20.5   | 23.5 | 26.5 | dB    |      |
| 14 | Channel Crosstalk         | CT  | 1            | Po=0.5W, Vol=1.25V                      | 40     | 55   | -    | dB    |      |

Note 1) For this measurement, use the BPF = 15Hz ~ 30kHz (12dB/OCT).

|             |             |           |           |
|-------------|-------------|-----------|-----------|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |
| 25-APR-2000 | 21-JUL-2000 |           |           |

|          |  |  |            |     |
|----------|--|--|------------|-----|
| Prepared |  | <b>Product Specifications</b><br>(Reference Data for Design)<br><b>AN7522N</b> | Ref No.    | B-2 |
| Checked  |  |  | Total Page | 9   |
| Approved |  |  | Page No.   | 3   |

| B  |                     | Electrical Characteristics (Unless otherwise specified, the ambient temperature is 25°C±2°C, Vcc=8.0V, frequency=1kHz and RL=8Ω.) |              |                 |        |     |     |      |      |
|----|---------------------|---|--------------|-----------------|--------|-----|-----|------|------|
| No | Item                | Symbol  | Test Circuit | Conditions      | Limits |     |     | Unit | Note |
|    |                     |   |              |                 | min    | typ | max |      |      |
| 1  | Standby pin current | ISTB2   | 1            | Vin=0V, VSTB=3V | -      | -   | 25  | μA   |      |
| 2  | Volume pin current  | IVOL  | 1            | Vin=0V, Vol=0V  | -12    | -   | -   | μA   |      |
| 3  | Input Impedance     | Zi  | 1            | Vin=±0.3VDC     | 24     | 30  | 36  | kΩ   |      |

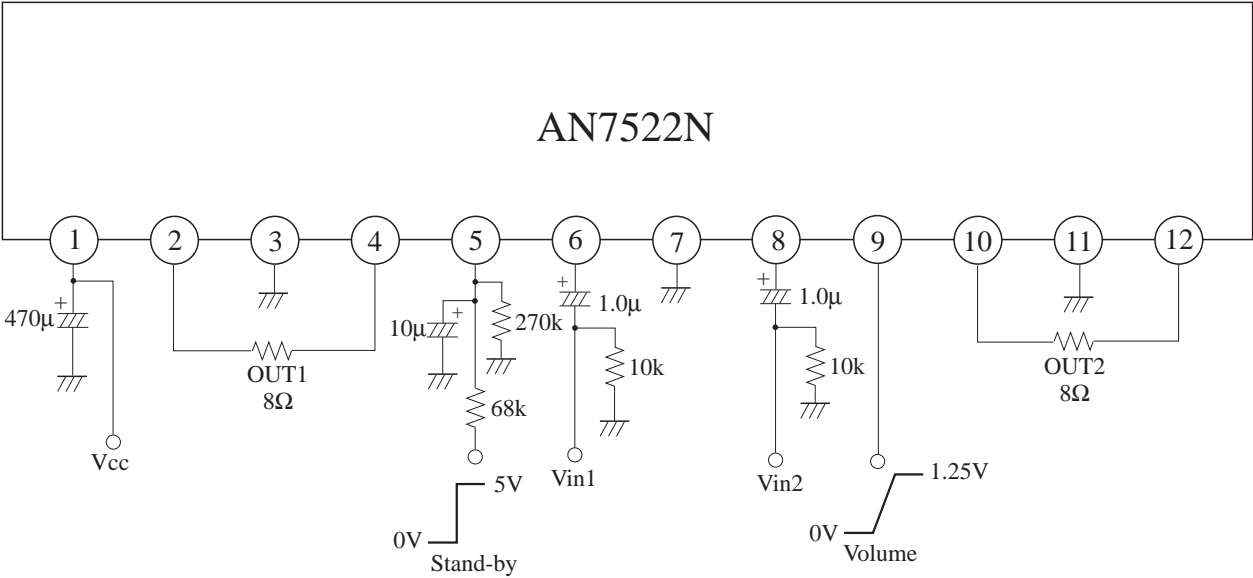
Note) The above characteristics are reference values determined for IC design, but not guaranteed values for shipping inspection. If problems were to occur, counter measures will be sincerely discussed.

|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |   |            |     |
|----------|--|---|------------|-----|
| Prepared |  | <div>Product Specifications</div> <div><b>AN7522N</b></div> | Ref No.    | C-1 |
| Checked  |  |   | Total Page | 9   |
| Approved |  |   | Page No.   | 4   |

(Description of test circuit and test method)

Test Circuit 1

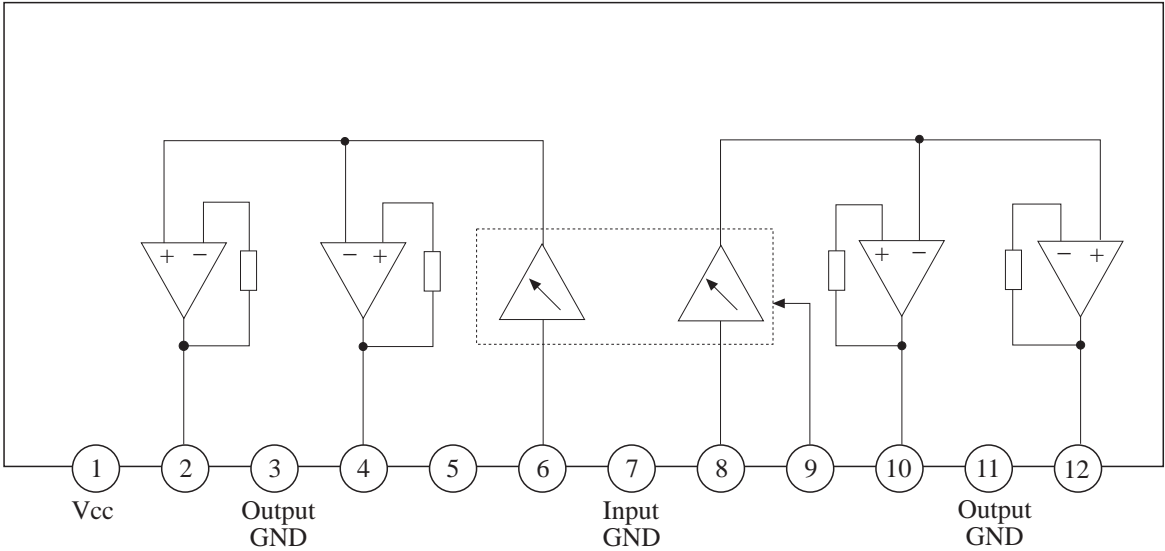


Note) If the standby pin is open or 0V, the IC is on standby state.  
The IC is in the state of volume minimum if the Volume pin is ground.  
The IC is in the state of volume maximum if the Volume pin is open.

|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |  |            |     |
|----------|--|--|------------|-----|
| Prepared |  | <div>Product Specifications</div> <div>AN7522N</div> | Ref No.    | D-1 |
| Checked  |  |  | Total Page | 9   |
| Approved |  |  | Page No.   | 5   |

Circuit Function Block Diagram



Pin Descriptions

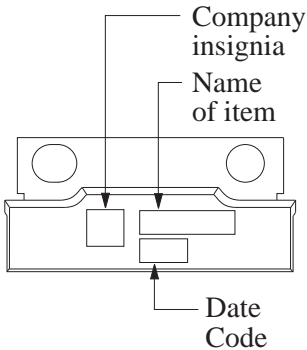
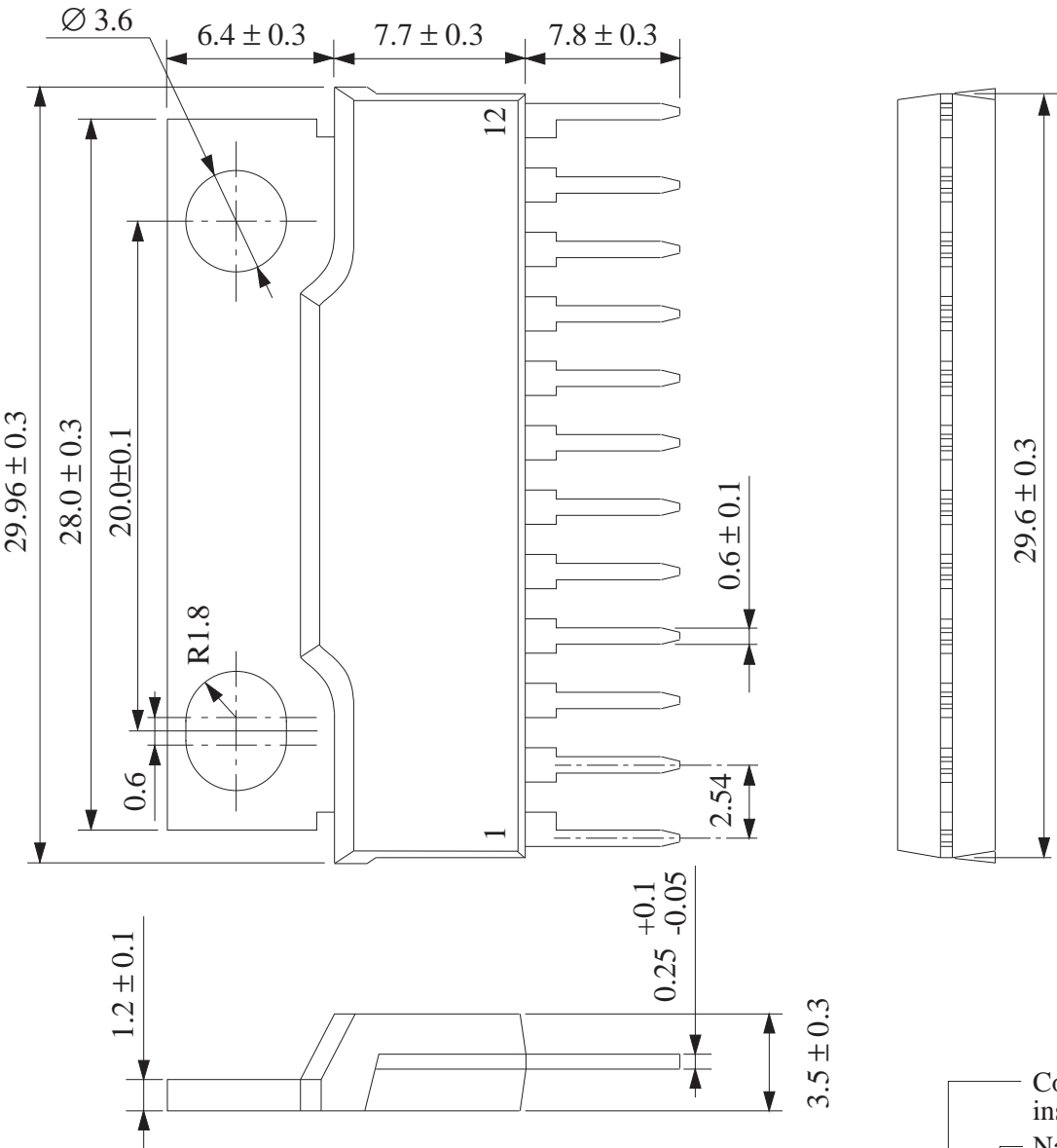
| Pin No. | Description       | Pin No. | Description       |
|---------|-------------------|---------|-------------------|
| 1       | Vcc               | 7       | GND (Input)       |
| 2       | Ch.1 Output (+)   | 8       | Ch.2 Input        |
| 3       | GND (Ch.1 Output) | 9       | Volume            |
| 4       | Ch.1 Output (-)   | 10      | Ch.2 Output (-)   |
| 5       | Standby           | 11      | GND (Ch.2 Output) |
| 6       | Ch.1 Input        | 12      | Ch.2 Output (+)   |

|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |  |            |   |
|----------|--|--|------------|---|
| Prepared |  | <div>Product Specifications</div> <div>AN7522N</div> | Ref No.    | E |
| Checked  |  |  | Total Page | 9 |
| Approved |  |  | Page No.   | 6 |

|              |        |
|--------------|--------|
| Package Name | FP-12S |
|--------------|--------|

Unit : mm



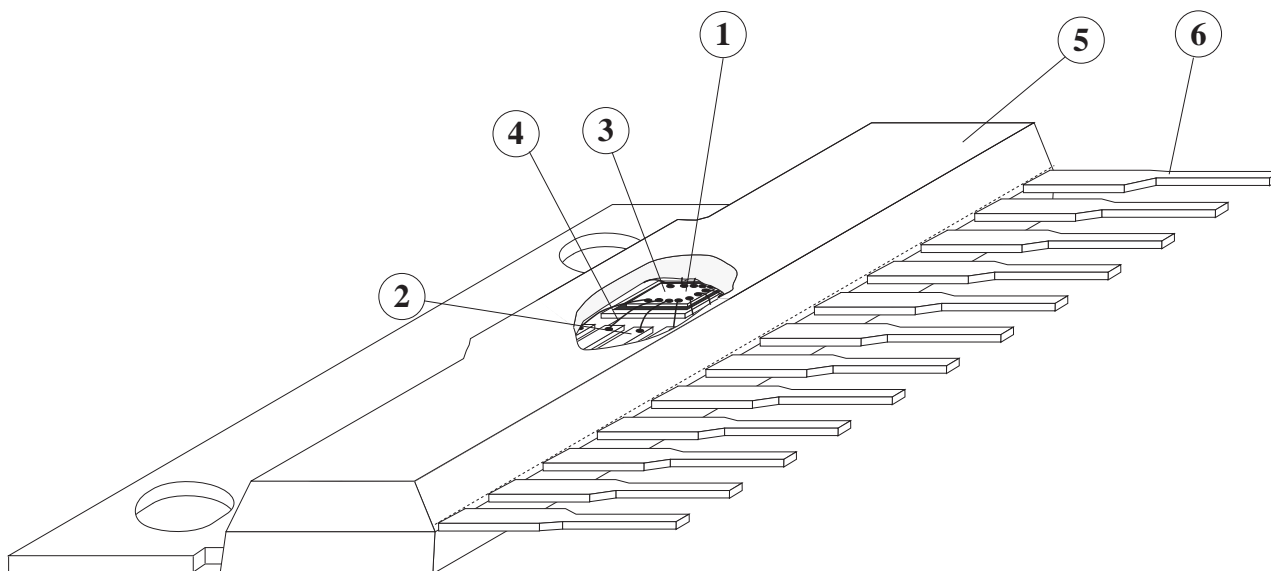
|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |   |            |     |
|----------|--|---|------------|-----|
| Prepared |  | <b>Product Specifications</b><br><b>AN7522N</b> | Ref No.    | F-1 |
| Checked  |  |   | Total Page | 9   |
| Approved |  |   | Page No.   | 7   |

### (Structure Description)

|                            |                       |                    |                    |      |
|----------------------------|-----------------------|--------------------|--------------------|------|
| Chip surface passivation   | SiN,                  | PSG,               | Others ( )         | ①    |
| Lead frame material        | Fe group,             | Cu group,          | Others ( )         | ②, ⑥ |
| Inner lead surface process | Ag plating,           | Au plating,        | Others ( )         | ②    |
| Outer lead surface process | Solder plating,       | Solder dip,        | Others ( )         | ⑥    |
| Chip mounting method       | Ag paste,             | Au-Si alloy,       | Solder, Others ( ) | ③    |
| Wire bonding method        | Thermalsonic bonding, |                    | Others ( )         | ④    |
| Wire material, Diameter    | Au,                   | Diameter 38 μm     | Others ( )         | ④    |
| Mold material              | Epoxy,                |                    | Others ( )         | ⑤    |
| Molding method             | Transfer mold,        | Multiplunger mold, | Others ( )         | ⑤    |
| Fin material               | Cu Group              |                    | Others ( )         | ⑦    |

### Package FP-12S

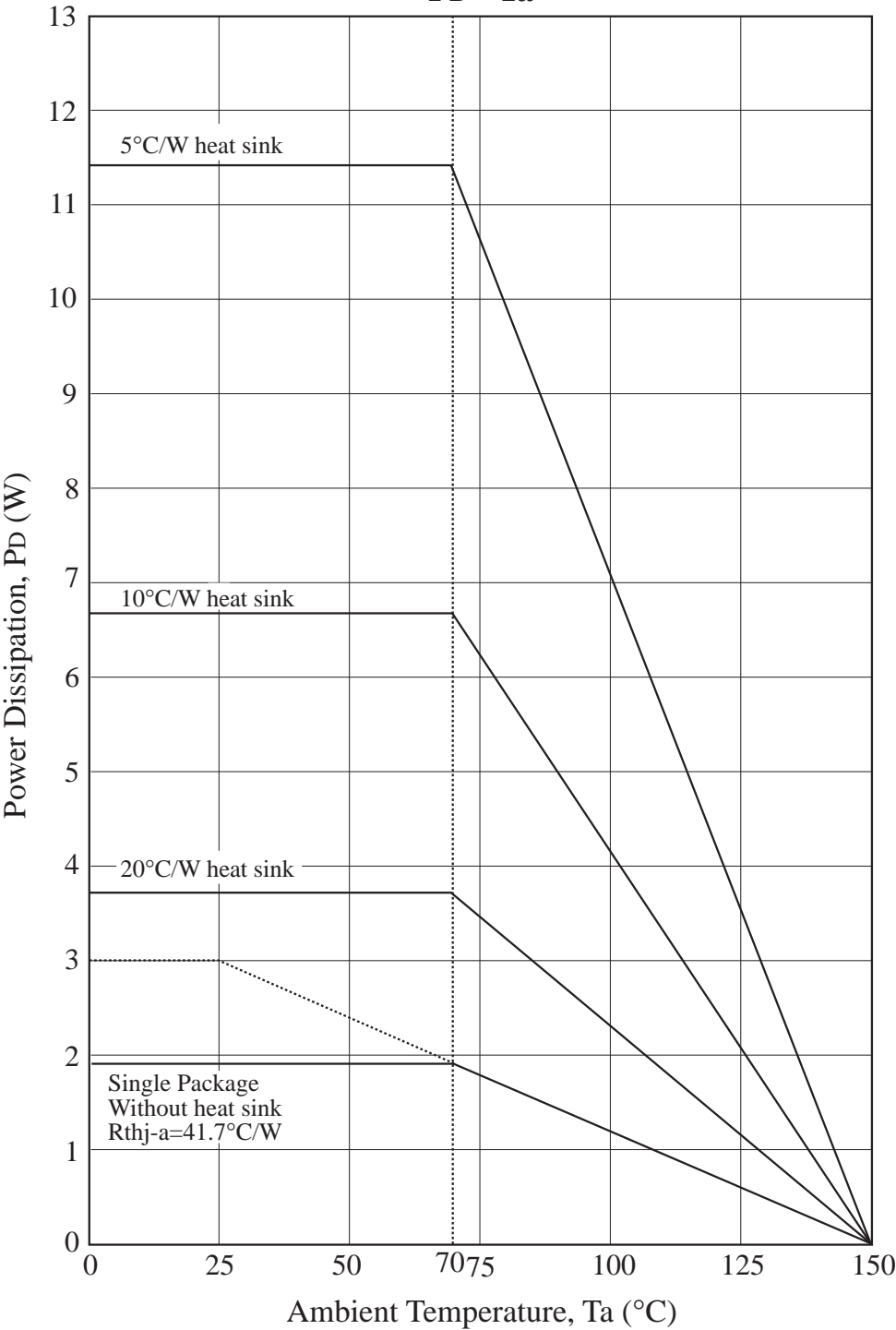


|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |   |            |   |
|----------|--|---|------------|---|
| Prepared |  | <b>Product Specifications</b><br>(Technical Data)<br><b>AN7522N</b> | Ref No.    | G |
| Checked  |  |   | Total Page | 9 |
| Approved |  |   | Page No.   | 8 |

$$\left( \begin{array}{l} R_{th(j-c)} = 2^{\circ}\text{C/W} \\ R_{th(j-a)} = 41.7^{\circ}\text{C/W} \end{array} \right)$$

FP-12S Package Power Dissipation  
**P<sub>D</sub> - T<sub>a</sub>**



|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |

|          |  |   |            |   |
|----------|--|---|------------|---|
| Prepared |  | <b>Product Specifications</b><br>(Technical Data)<br><b>AN7522N</b> | Ref No.    | G |
| Checked  |  |   | Total Page | 9 |
| Approved |  |   | Page No.   | 9 |

### (Precautions for use)

- 1) Make sure that the IC is free of any pin short-circuiting, ground short, and load short-circuiting.
- 2) Ground the radiation fin so that there will be no difference in electric potential between the radiation fin and ground.
- 3) The thermal protection circuit operates at a Tj of approximately 150°C. The thermal protection circuit is reset automatically when the temperature drops.
- 4) Make sure that the heat radiation design is effective enough if the Vcc is comparatively high or the IC operates high output power.
- 5) Connect only ground pin for signal sources to the signal GND pin of the amplifier on the previous stage.
- 6) The electric surge voltage for this IC low, therefore be extra careful when using the following pin (at 200pF):  
Pin 5=+140V, Pin 6=+140V, Pin 9=+130V, Pin 8=+150V

|             |             |           |           |  |
|-------------|-------------|-----------|-----------|--|
| Eff. Date   | Eff. Date   | Eff. Date | Eff. Date |  |
| 25-APR-2000 | 21-JUL-2000 |           |           |  |